NSN 5961-01-291-9420

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-291-9420

Inclosure Material:	
Metal	
Overall Length:	
Between 0.184 inches and 0.260) inches
Terminal Length:	
1.500 inches	
Overall Diameter:	
Between 0.335 inches and 0.370) inches
End Application:	
1520-01-035-0266	
Internal Configuration:	
Junction contact-darlington conn	ected
Joint Electronic Device Engine	eering Council/jedec/case Outline Designation:
То-33	
Electrode Internally-electrically	y Connected To Case:
Collector	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Semiconductor Material:	
Silicon	
/oltage Rating In Volts Per Ch	aracteristic:
80.0 collector-to-emitter, resista	ince between base and emitter
Current Rating Per Characteris	stic:
5.00 amperes source cutoff curre	ent
Power Rating Per Characterist	ic:
5.0 watts small-signal input powe	er, common-collector absolute
Maximum Operating Tempurat	ure Per Measurement Point:
200.0 degrees celsius ambient a	ir
Special Features:	
Base (b2) lead cut to 0.100 in.;	junction pattern arrangement: npn
Precious Material And Location	n:
Terminal surface option gold	
Precious Material:	
Gold	
Test Data Document:	
81349-mil-s-19500 specification	(includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
	talogs, industry directories, and similar trade publications, reflecting general type data on certain
	requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:	
4 uninsulated wire lead	

Specification Data:

4 uninsulated wire lead

81349-mil-s-19500/472 government specification

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

